

CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9 8,192 x 9, 16,384 x 9 32,768 x 9 and 65,536 x 9

IDT7203 IDT7204 IDT7205 IDT7206 IDT7207 IDT7208

FEATURES:

- First-In/First-Out Dual-Port memory
- 2,048 x 9 organization (IDT7203)
- 4,096 x 9 organization (IDT7204)
- 8,192 x 9 organization (IDT7205)
- 16,384 x 9 organization (IDT7206)
 22,770 x 9 organization (IDT7207)
- 32,768 x 9 organization (IDT7207)
- 65,636 x 9 organization (IDT7208)
- High-speed: 12ns access time
- Low power consumption
 - Active: 660mW (max.)
 - Power-down: 44mW (max.)
- Asynchronous and simultaneous read and write
- Fully expandable in both word depth and width
- Pin and functionally compatible with IDT720X family
- Status Flags: Empty, Half-Full, Full
- · Retransmit capability
- High-performance CMOS technology
- Military product compliant to MIL-STD-883, Class B
- Standard Military Drawing for #5962-88669 (IDT7203), 5962-89567 (IDT7203), and 5962-89568 (IDT7204) are listed on this function

FUNCTIONAL BLOCK DIAGRAM

- Industrial temperature range (-40°C to +85°C) is available (plastic packages only)
- Green parts available, see ordering information

DESCRIPTION:

The IDT7203/7204/7205/7206/7207/7208 are dual-port memory buffers with internal pointers that load and empty data on a first-in/first-out basis. The device uses Full and Empty flags to prevent data overflow and underflow and expansion logic to allow for unlimited expansion capability in both word size and depth.

Data is toggled in and out of the device through the use of the Write (\overline{W}) and Read (\overline{R}) pins.

The device's 9-bit width provides a bit for a control or parity at the user's option. It also features a Retransmit (\overline{RT}) capability that allows the read pointer to be reset to its initial position when \overline{RT} is pulsed LOW. A Half-Full Flag is available in the single device and width expansion modes.

These FIFOs are fabricated using IDT's high-speed CMOS technology. They are designed for applications requiring asynchronous and simultaneous read/writes in multiprocessing, rate buffering and other applications.

Military grade product is manufactured in compliance with the latest revision of MIL-STD-883, Class B.



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COMMERCIAL, MILITARY AND INDUSTRIAL TEMPERATURE RANGES

PIN CONFIGURATIONS



TOP VIEW



TOP VIEW

	Reference	Order	Device
Package Type	Identifier	Code	Availability
PLASTIC DIP	P28-1	Р	All devices
PLASTIC THIN DIP	P28-2	TP	All except IDT7207/7208
CERDIP	D28-1	D	All except IDT7208
THIN CERDIP	D28-3	TD	Only for IDT7203/7204/7205
SOIC	SO28-3	SO	Only for IDT7204

Package Type	Reference Identifier	Order Code	Device Availability
PLCC	J32-1	J	All devices
LCC ⁽¹⁾	L32-1	L	All except IDT7208

NOTE:

1. This package is only available in the military temperature range.

ABSOLUTE MAXIMUM RATINGS

Symbol	Rating	Com'l & Ind'l	Military	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
TSTG	Storage Temperature	-55 to + 125	–65 to +155	°C
Іоит	DC Output +Current	-50 to +50	-50 to +50	mA

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vcc	Supply Voltage Commercial/Industrial/Military	4.5	5.0	5.5	V
GND	Supply Voltage	0	0	0	V
Vih ⁽¹⁾	Input High Voltage Commercial/Industrial	2.0	_		۷
VIH ⁽¹⁾	Input High Voltage Military	2.2	_	-	٧
Vil ⁽²⁾	Input Low Voltage Commercial/Industrial/Military	-	—	0.8	V
TA	Operating Temperature Commercial	0	_	70	°C
Та	Operating Temperature Industrial	-40	_	85	°C
TA	Operating Temperature Military	-55	_	125	°C

NOTES:

- 1. For $\overline{RT}/\overline{RS}/\overline{XI}$ input, VIH = 2.6V (commercial).
- For $\overline{RT}/\overline{RS}/\overline{XI}$ input, VIH = 2.6V (military).
- 2. 1.5V undershoots are allowed for 10ns once per cycle.

DC ELECTRICAL CHARACTERISTICS

(Commercial: Vcc = 5V \pm 10%, TA = 0°C to +70°C; Industrial: Vcc = 5V \pm 10%, TA = -40°C to +85°C; Military: Vcc = 5V \pm 10%, TA = -55°C to +125°C)

		Comm ta = 12	IDT7203 ⁽¹⁾ IDT7204 ⁽¹⁾ ercial and Ind , 15, 20, 25, 35	ustrial , 50 ns	IDT7203 IDT7204 Military ⁽³⁾ tA = 20, 30, 40 ns			
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
ILI ⁽⁶⁾	Input Leakage Current (Any Input)	-1	_	1	-1	_	1	μA
1LO ⁽⁷⁾	Output Leakage Current	-10	_	10	-10	_	10	μA
Voн	Output Logic "1" Voltage Іон = –2mA	2.4	_	ĺ	2.4	_	—	V
Vol	Output Logic "0" Voltage IoL = 8mA	—	_	0.4	_	—	0.4	V
ICC1 ^(8,9,10)	Active Power Supply Current	_	_	120	_	—	150	mA
ICC2 ^(8,10,11)	Standby Current ($\overline{R}=\overline{W}=\overline{R}S=\overline{FL}/\overline{R}T=VIH$)	_	_	12	—	—	25	mA
ICC3 ^(8,10,12)	Power Down Current	—	_	2	_	—	4	mA
		IDT7205 ⁽²⁾ IDT7206 ^(2,4) IDT7207 ^(2,4) IDT7208 ^(2,5) Commercial and Industrial tA = 12, 15, 20, 25, 35, 50 ns			IDT7205 IDT7206 IDT7207 Military ta = 20, 30 ns			
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
1LI ⁽⁶⁾	Input Leakage Current (Any Input)	-1		1	-1		1	μA
ILO ⁽⁷⁾	Output Leakage Current	-10	_	10	-10	_	10	μA
Vон	Output Logic "1" Voltage Iон = -2mA	2.4	_	_	2.4	_		V
Vol	Output Logic "0" Voltage IoL = 8mA	_	_	0.4	_	_	0.4	V
ICC1 ^(8,9,10)	Active Power Supply Current	_	_	120	_	_	150	mA
ICC2 ^(8,10,11)	Standby Current (RS=FL/RT=VIH)	_	_	12	_	_	25	mA
ICC3 ^(8,10,12)	Power Down Current	_	_	8	_	_	12	mA

NOTES:

- 1. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device.
- 2. Industrial temperature range product for 25ns speed grade only is available as a standard device. All other speed grades are available by special order.
- 3. Military temperature range product for the 40ns is only available for 7203.
- 4. Commercial temperature range product for the 12ns not available.
- 5. Commercial temperature range product for the 12ns, 15ns and 50ns not available.
- 6. Measurements with $0.4 \leq V_{IN} \leq V_{CC}$.
- 7. $\overline{R} \ge V_{IH}$, $0.4 \le V_{OUT} \le V_{CC}$.
- 8. Tested with outputs open (IOUT = 0).
- 9. \overline{R} and \overline{W} toggle at 20 MHz and data inputs switch at 10 MHz.
- 10. Icc measurements are made with outputs open.
- 11. All Inputs = Vcc \cdot 0.2V or GND + 0.2V, except \overline{R} and \overline{W} , which toggle at 20MHz.
- 12. All Inputs = Vcc 0.2V or GND + 0.2V, except \overline{R} and \overline{W} = Vcc -0.2V.

AC TEST CONDITIONS

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	See Figure 1

CAPACITANCE⁽¹⁾ (T_A = +25°C, f = 1.0 MHz)

Symbol	Parameter	Condition	Max.	Unit
CIN ⁽¹⁾	Input Capacitance	VIN = 0V	10	pF
COUT ^(1,2)	Output Capacitance	Vout = 0V	10	pF
NOTEC				

- NOTES:
- 1. This parameter is sampled and not 100% tested.

2. With output deselected.



or equivalent circuit

Figure 1. Output Load *Includes jig and scope capacitances.

AC ELECTRICAL CHARACTERISTICS⁽¹⁾

(Commercial: Vcc = $5V \pm 10\%$, TA = 0°C to +70°C; Industrial: Vcc = $5V \pm 10\%$, TA = -40°C to +85°C; Military: Vcc = $5V \pm 10\%$, TA = -55°C to +125°C)

		Com	nercial	Com'l	& Ind'l	Com'l &	Military	Comr	nercial	Com'l	& Ind'l	
		IDT72	203L12 2041 12		03L15 ⁽²⁾ 041 15 ⁽²⁾	IDT72	03L20 041 20	IDT72	208L20		03L25 ⁽²⁾ 041 25 ⁽²⁾	
		IDT72	205L12	IDT72	05L15	IDT72	05L20			IDT72	05L25 ⁽³⁾	
				IDT72	06L15	IDT72	06L20			IDT72	06L25 ⁽³⁾	
					U/L15	10172	07L20			IDT72	D7L25 ⁽³⁾ D8L25 ⁽³⁾	
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fs	Shift Frequency		50	_	40	_	33.3		33.3	_	28.5	MHz
tRC	Read Cycle Time	20	_	25	_	30	_	30	_	35	_	ns
tA	Access Time		12	_	15	_	20	_	20	_	25	ns
tRR	Read Recovery Time	8	_	10	_	10	_	10		10	—	ns
tRPW	Read Pulse Width ⁽⁴⁾	12	_	15	_	20	_	20	_	25	_	ns
tRLZ	Read LOW to Data Bus LOW ⁽⁵⁾	3	_	5	_	5	—	5	_	5	_	ns
twLz	Write HIGH to Data Bus Low-Z ^(5,6)	3	_	5	_	5	—	5	_	5	—	ns
tDV	Data Valid from Read HIGH	5	_	5	—	5	-	5	—	5	_	ns
tRHZ	Read HIGH to Data Bus High-Z ⁽⁵⁾	_	12	-	15	_	15	_	15	—	18	ns
twc	Write Cycle Time	20	_	25	_	30	-	30	—	35	_	ns
twpw	Write Pulse Width ⁽⁴⁾	12		15	_	20		20	_	25	_	ns
twr	Write Recovery Time	8	—	10	—	10	—	10	_	10	—	ns
tDS	Data Set-up Time	9		11	—	12	-	12	—	15	_	ns
tDH	Data Hold Time	0	_	0	—	0	—	0	—	0	_	ns
tRSC	Reset Cycle Time	20		25	_	30		30	_	35	_	ns
tRS	Reset Pulse Width ⁽⁴⁾	12	_	15	_	20	—	20	_	25	_	ns
tRSS	Reset Set-up Time ⁽⁵⁾	12		15	-	20		20	_	25	_	ns
trtr	Reset Recovery Time	8	_	10	_	10		10	—	10	_	ns
trtc	Retransmit Cycle Time	20	-	25	_	30		30	_	35	_	ns
tRT	Retransmit Pulse Width ⁽⁴⁾	12		15	_	20		20	—	25	—	ns
trts	Retransmit Set-up Time ⁽⁵⁾	12	—	15	—	20	—	20	—	25	_	ns
trtr	Retransmit Recovery Time	8	_	10	_	10	—	10	_	10	_	ns
tefl	Reset to EF LOW	—	12		25	_	30		30	_	35	ns
thfh, tffh	Reset to HF and FF HIGH	—	17	—	25	_	30		30	—	35	ns
t RTF	Retransmit LOW to Flags Valid		20	_	25		30		30		35	ns
tref	Read LOW to EF LOW		12	_	15		20		20		25	ns
tRFF	Read HIGH to FF HIGH		14	_	15		20		20		25	ns
t RPE	Read Pulse Width after EF HIGH	12		15		20		20		25		ns
twef	Write HIGH to EF HIGH	—	12	_	15		20		20		25	ns
twff	Write LOW to FF LOW		14		15		20		20		25	ns
twhf	Write LOW to HF Flag LOW		17		25		30		30		35	ns
trhf	Read HIGH to HF Flag HIGH		17		25		30		30		35	ns
twpf	Write Pulse Width after FF HIGH	12		15		20		20		25		ns
txol	Read/Write LOW to XO LOW		12		15		20		20		25	ns
tхон	Read/Write HIGH to \overline{XO} HIGH	—	12	_	15		20		20	_	25	ns
txi	XI Pulse Width ⁽⁴⁾	12		15		20		20		25		ns
txir	XI Recovery Time	8		10		10		10		10		ns
txis	XI Set-up Time	8	_	10	_	10	—	10	_	10	_	ns

NOTES:

1. Timings referenced as in AC Test Conditions.

2. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device.

Industrial temperature range product for 25ns spece grade only is available as a standard device. All other speed grades are available by special order.
 Pulse widths less than minimum are not allowed.
 Values guaranteed by design, not currently tested.
 Only applies to read data flow-through mode.

AC ELECTRICAL CHARACTERISTICS⁽¹⁾ (CONTINUED)

(Commercial: $VCC = 5V \pm 10\%$, $TA = 0^{\circ}C$ to $+70^{\circ}C$; Industrial: $VCC = 5V \pm 10\%$, $TA = -40^{\circ}C$ to $+85^{\circ}C$; Military: $VCC = 5V \pm 10\%$, $TA = -55^{\circ}C$ to $+125^{\circ}C$)

		Military		Commercial		Military		Commercial		
		IDT7	203L30	IDT72	03L35	IDT72	03L40	IDT72	03L50	
		IDT7	204L30	IDT72	04L35			IDT72	04L50	
		IDT7	205L30	IDT 7 2	05L35			IDT72	05L50	
		IDT7	206L30	IDT72	06L35			IDT72	06L50	
		IDT7	207L30	IDT72	07L35 00L35			ID172	07L50	
				10172	00133					
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
ts	Shift Frequency	-	25	-	22.22	-	20	-	15	MHZ
tRC	Read Cycle Time	40	—	45	_	50	_	65	—	ns
tA	Access lime		30		35	—	40		50	ns
tRR	Read Recovery Time	10	—	10	_	10	_	15	—	ns
tRPW	Read Pulse Width ⁽²⁾	30	_	35	—	40	_	50	_	ns
trlz	Read LOW to Data Bus LOW ⁽³⁾	5	_	5	_	5	_	10	_	ns
twlz	Write HIGH to Data Bus Low-Z ^(3,4)	5		10	_	10	_	15		ns
tDV	Data Valid from Read HIGH	5	_	5		5		5	_	ns
tRHZ	Read HIGH to Data Bus High-Z ⁽³⁾		20		20	_	25		30	ns
twc	Write Cycle Time	40	_	45		50		65	_	ns
twpw	Write Pulse Width ⁽²⁾	30	—	35	_	40	_	50	_	ns
twr	Write Recovery Time	10	—	10		10		15	—	ns
tDS	Data Set-up Time	18	_	18	_	20	_	30	_	ns
tDH .	Data Hold Time	0	_	0		0		5	_	ns
tRSC	Reset Cycle Time	40		45		50		65	_	ns
tRS	Reset Pulse Width ⁽²⁾	30		35		40		50	_	ns
tRSS	Reset Set-up Time ⁽³⁾	30		35		40		50	_	ns
trtr	Reset Recovery Time	10		10		10		15		ns
trtc	Retransmit Cycle Time	40	_	45		50		65	_	ns
trt	Retransmit Pulse Width ⁽²⁾	30		35	_	40	_	50	_	ns
trts	Retransmit Set-up Time ⁽³⁾	30	_	35	_	40	_	50	—	ns
trtr	Retransmit Recovery Time	10		10		10		15	_	ns
tefl	Reset to EF LOW	_	40	_	45	_	50	_	65	ns
thfh, tffh	Reset to HF and FF HIGH	_	40	_	45	_	50	_	65	ns
trtf	Retransmit LOW to Flags Valid	_	40	_	45	_	50	_	65	ns
tref	Read LOW to EF LOW	_	30	_	30	_	35	_	45	ns
tRFF	Read HIGH to FF HIGH	_	30	_	30	_	35	_	45	ns
tRPE	Read Pulse Width after EF HIGH	30		35		40	_	50	_	ns
twef	Write HIGH to EF HIGH	_	30		30	_	35	_	45	ns
twff	Write LOW to FF LOW	_	30		30	_	35	_	45	ns
twhf	Write LOW to HF Flag LOW	_	40	—	45	_	50	_	65	ns
tRHF	Read HIGH to HF Flag HIGH	_	40	_	45	_	50	_	65	ns
twpf	Write Pulse Width after FF HIGH	30	_	35	_	40	_	50	_	ns
txol	Read/Write LOW to XO LOW	_	30	_	35	_	40	_	50	ns
tхон	Read/Write HIGH to XO HIGH	_	30		35	_	40	_	50	ns
txi	XI Pulse Width ⁽²⁾	30	—	35	_	40	_	50	—	ns
txir	XI Recovery Time	10	_	10	_	10	_	10	—	ns
txis	XI Set-up Time	10	_	15	_	15	_	15	_	ns

NOTES:

Timings referenced as in AC Test Conditions.
 Pulse widths less than minimum are not allowed.
 Values guaranteed by design, not currently tested.
 Only applies to read data flow-through mode.

ORDERING INFORMATION



NOTES:

- 1. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device for IDT7203/7204, and 25ns speed grade only is available as a standard device for IDT7205/7206/7207/7208. All other speed grades are available by special order.
- 2. The LCC is only available in the military temperature range.
- 3. The IDT7208 is only available in commercial speed grades of 20, 25 and 35 ns.
- 4. Green parts are available. For specific speeds and packages contact your local sales office.
- 5. For "P", Plastic Dip, when ordering green package, the suffix is "PDG".